

## Single Non-Inverting Buffer with Open Drain Output

The NL17SZ07 is a high performance single inverter with open drain outputs operating from a 1.65 to 5.5 V supply.

The Output stage is open drain with Over Voltage Tolerance. This allows the NL17SZ07 to be used to interface 5.0 V circuits to circuits of any voltage between 0 and +7.0 V.

- Tiny SOT-353 and SOT-553 Packages
- Extremely High Speed:  $t_{PD}$  2.5 ns (typical) at  $V_{CC} = 5$  V
- Designed for 1.65 V to 5.5 V  $V_{CC}$  Operation, CMOS Compatible
- Over Voltage Tolerant Inputs  $V_{IN}$  may be Between 0 and 7.0 V for  $V_{CC}$  Between 0.5 and 5.4 V
- TTL Compatible – Interface Capability with 5.0 V TTL Logic with  $V_{CC} = 2.7$  V to 3.6 V
- LVCMS Compatible
- 24 mA Output Sink Capability, Pullup may be between 0 and 7.0 V
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 20
- Pb-Free Packages are Available

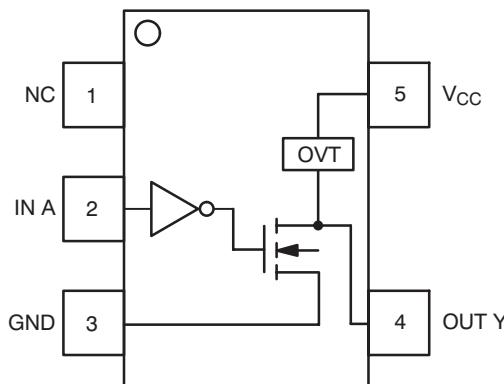


Figure 1. Pinout



Figure 2. Logic Symbol



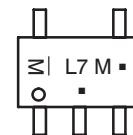
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<http://onsemi.com>

### MARKING DIAGRAM



SC-88A / SOT-353 / SC-70  
DF SUFFIX  
CASE 419A



SOT-553  
XV5 SUFFIX  
CASE 463B

L7 = Device Code  
M = Date Code\*  
- = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

### PIN ASSIGNMENT

Pin	Function
1	NC
2	IN A
3	GND
4	OUT Y
5	$V_{CC}$

### FUNCTION TABLE

A Input	Y Output
L	L
H	Z

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

## MAXIMUM RATINGS

Symbol	Characteristics	Value	Unit
$V_{CC}$	DC Supply Voltage	−0.5 to +7.0	V
$V_I$	DC Input Voltage	$-0.5 \leq V_I \leq +7.0$	V
$V_O$	DC Output Voltage Output in Z or LOW State (Note 1)	$-0.5 \leq V_O \leq 7.0$	V
$I_{IK}$	DC Input Diode Current $V_I < GND$	−50	mA
$I_{OK}$	DC Output Diode Current $V_O < GND$	−50	mA
$I_O$	DC Output Sink Current	$\pm 50$	mA
$I_{CC}$	DC Supply Current per Supply Pin	$\pm 100$	mA
$I_{GND}$	DC Ground Current per Ground Pin	$\pm 100$	mA
$T_{STG}$	Storage Temperature Range	−65 to +150	°C
$P_D$	Power Dissipation in Still Air SOT-353 SOT-553	186 135	mW
$\theta_{JA}$	Thermal Resistance SOT-353 SOT-553	350 496	°C/W
$T_L$	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
$T_J$	Junction Temperature Under Bias	+150	°C
$I_{Latch-Up}$	Latch-Up Performance Above $V_{CC}$ and Below GND at 85°C (Note 5)	$\pm 500$	mA
MSL	Moisture Sensitivity	Level 1	
$F_R$	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	Class IC Class A N/A	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1.  $I_O$  absolute maximum rating must be observed.
2. Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
3. Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
4. Tested to JESD22-C101-A.
5. Tested to EIA/JESD78.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
$V_{CC}$	Supply Voltage Operating Data Retention Only	1.65 1.5	5.5 5.5	V
$V_I$	Input Voltage	0	5.5	V
$V_O$	Output Voltage (Z or LOW State)	0	5.5	V
$T_A$	Operating Free-Air Temperature	−55	+125	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	20 10 5	ns/V

## DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.7 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.7 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.3 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.3 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
I <sub>LKG</sub>	Z-State Output Leakage Current	V <sub>IN</sub> = V <sub>IH</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	2.3 to 5.5			±5.0		±10.0	µA
V <sub>OL</sub>	Low-Level Output Voltage V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 100 µA	1.65 to 5.5		0.0	0.1		0.1	V
		I <sub>OL</sub> = 4 mA	1.65		0.08	0.24		0.24	
		I <sub>OL</sub> = 8 mA	2.3		0.20	0.3		0.3	
		I <sub>OL</sub> = 12 mA	2.7		0.22	0.4		0.4	
		I <sub>OL</sub> = 16 mA	3.0		0.28	0.4		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.38	0.55		0.55	
		I <sub>OL</sub> = 32 mA	4.5		0.42	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> or V <sub>OUT</sub> = V <sub>CC</sub> or GND	0 to 5.5			±0.1		±1.0	µA
I <sub>OFF</sub>	Power Off-Output Leakage Current	V <sub>OUT</sub> = 5.5 V	0			1		10	µA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5			1		10	µA
I <sub>CCT</sub>	Quiescent Supply Current	V <sub>IN</sub> = 3.0 V	3.6			10		100	µA

AC ELECTRICAL CHARACTERISTICS t<sub>R</sub> = t<sub>F</sub> = 2.5 ns; C<sub>L</sub> = 50 pF; R<sub>L</sub> = 500 Ω

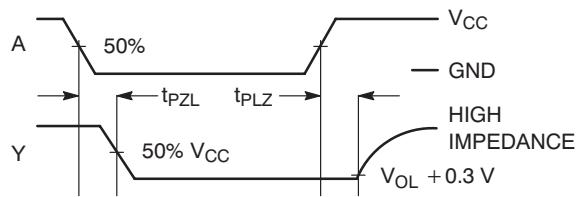
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-55°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t <sub>PZL</sub>	Propagation Delay (Figure 3 and 4)	R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	1.8 ± 0.15	0.8	5.3	11.6	0.8	12.0	ns
			2.5 ± 0.2	1.2	3.7	5.8	1.2	6.4	
			3.3 ± 0.3	0.8	2.9	4.4	0.8	4.8	
			5.0 ± 0.5	0.5	2.3	3.5	0.5	3.9	
t <sub>PLZ</sub>	Propagation Delay (Figure 3 and 4)	R <sub>L</sub> = R <sub>1</sub> = 500 Ω, C <sub>L</sub> = 50 pF	1.8 ± 0.15	0.8	5.3	11.6	0.8	1.20	ns
			2.5 ± 0.2	1.2	2.8	5.8	1.2	6.4	
			3.3 ± 0.3	0.8	2.1	4.4	0.8	4.8	
			5.0 ± 0.5	0.5	1.4	3.5	0.5	3.9	

## CAPACITIVE CHARACTERISTICS

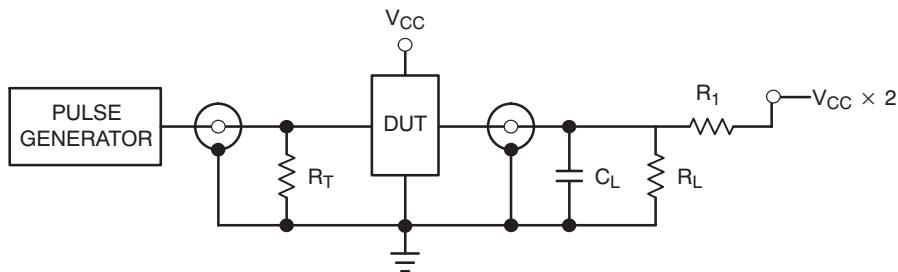
Symbol	Parameter	Condition	Typical	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	> 2.5	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	4.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	4.0	pF

6. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

**NL17SZ07**



**Figure 3. Switching Waveforms**



**Figure 4. Test Circuit**

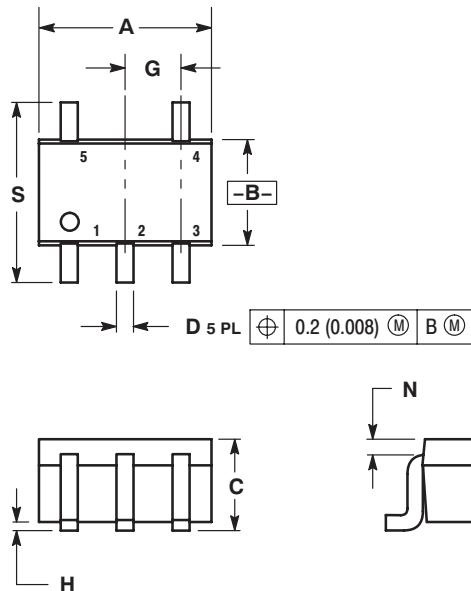
## DEVICE ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NL17SZ07DFT2	SOT-353/SC70-5/SC-88A	3000 / Tape & Reel
NL17SZ07DFT2G	SOT-353/SC70-5/SC-88A (Pb-Free)	3000 / Tape & Reel
NL17SZ07XV5T2	SOT-553	4000 / Tape & Reel
NL17SZ07XV5T2G	SOT-553 (Pb-Free)	4000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## PACKAGE DIMENSIONS

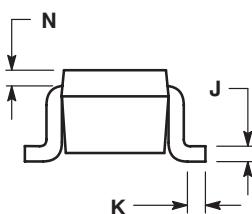
SC-88A, SOT-353, SC-70  
CASE 419A-02  
ISSUE J



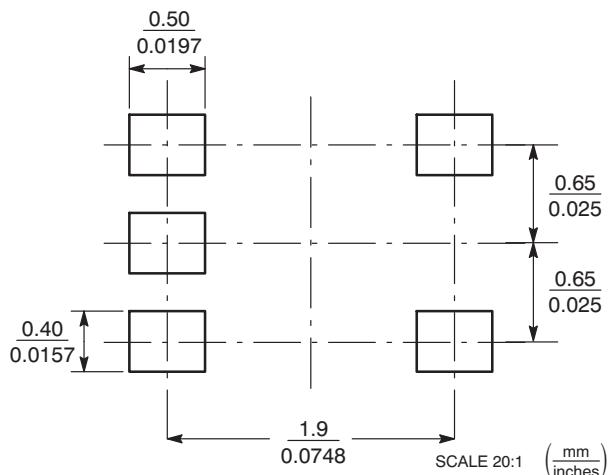
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.071	0.087	1.80	2.20
B	0.045	0.053	1.15	1.35
C	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
H	---	0.004	---	0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

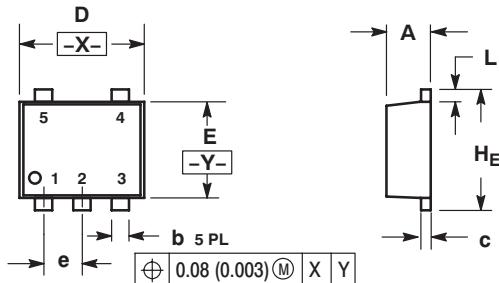


## SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

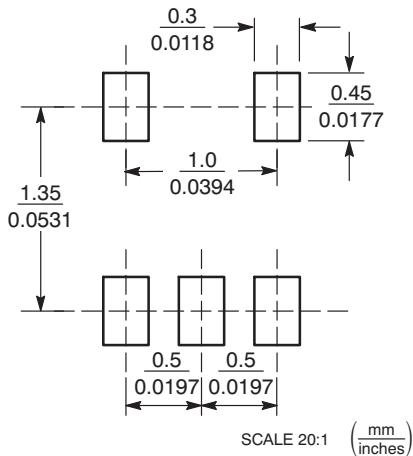
## PACKAGE DIMENSIONS

SOT-553, 5 LEAD  
CASE 463B-01  
ISSUE B

NOTES:  
 1. DIMENSIONING AND TOLERANCING PER  
 ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: MILLIMETERS  
 3. MAXIMUM LEAD THICKNESS INCLUDES  
 LEAD FINISH THICKNESS. MINIMUM LEAD  
 THICKNESS IS THE MINIMUM THICKNESS  
 OF BASE MATERIAL.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
c	0.08	0.13	0.18	0.003	0.005	0.007
D	1.50	1.60	1.70	0.059	0.063	0.067
E	1.10	1.20	1.30	0.043	0.047	0.051
e	0.50 BSC			0.020 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
H_E	1.50	1.60	1.70	0.059	0.063	0.067

## SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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